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Characterization of the proton beam at Cyrcé cyclotron using MIMOSIS-1 sensor

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Context

Experiment & methods

Results and Analysis

Discussion and Conclusion

Context of the internship

Problematic : Characterization of the proton beam at Cyrcé cyclotron using MIMOSIS-1 sensor

Hadrontherapy and DRHIM

Radiotherapy

- X-ray: common source, deposited dose is spread out
- Protons: stop at their target *(200 MeV proton in water → Bragg peak≈ 25 cm deep)*
- Effects of radiation protons need further investigation to ensure control of the dose deposit

Figure from ref. [1]

Hadrontherapy and DRHIM

- *Dose :* amount of energy deposited by unit mass
- *LET :* energy transferred locally by the particle to the material per unit length
- *Fluence :* Number of particle per unit surface

Contents Context Experiment & Results Discussion & Conclusion & Results Conclusion **Conclusion**

CBM and PICSEL

MIMOSIS-1

Monolithic Active Pixel Sensors (MAPS) in Complementary Metal–Oxide–Semiconductor (CMOS) technology

Designed and tested by the laboratory's microelectronics platform: **C4PI** (Centre de Compétence de Capteurs CMOS à Pixels Intégrés)

Carried by **PICSEL**

- Compressed Baryonic Matter at future Facility for Antiproton and Ion Research *in Darmstadt Germany*
- High density region of QCD phase diagram

Description of the MIMOSIS-1 sensor

Description of cyclotron of Cyrcé platform and its beamlines

Figure from ref. [5]

Figure from ref. [6]

Precy beamline : Transverse beam profile

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Description of the experiment

Collimator scan \rightarrow Fluence characterization Diameter : 2, 3, 5, 8, 10, 12, 15, 16.5 and 24 mm

Description of the experiment

Distance scan \rightarrow Dispersion characterization Distance: 14, 60, 110 and 162 mm

Description of the experiment

Clusterisation

Map of pixels (Binary output) for 1 frame \Box 5 µs

Clusterisation

Map of pixels (Binary output)

TAF : Telescope Framework Analysis (*Ref. [7]*)

→ created and managed by IPHC to characterize CMOS pixel and strip sensors

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Hit Maps for different collimators diameter

Motivation: Localized and controlled irradiation

Comparison of 2 measurements of intensity

Hit Maps and intensity comparison

Profiles in fluence (Y)

Motivation: Characterization of the beam

Dispersion as function of distance

Motivation: Characterization of the beam

Dispersion as function of distance

Motivation: Characterization of the beam

$$
erf(x) = \frac{1}{\sigma\sqrt{2\pi}} \int_0^x e^{-\left(\frac{1}{2}\frac{x'-\mu}{\sigma}\right)^2} dx
$$

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Dispersion as function of distance

Motivation: Characterization of the beam

Comparison between dose and fluence

Motivation: Characterization of the beam

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REFERENCES

- [1] Hiroki Shirato. Spearheading global fight against cancer with proton therapy. Vol.2 New Era of Radiation Therapy to Fight Cancer. October 2020.
- $\lceil 2 \rceil$ Gert Aarts, Felipe Attanasio, Benjamin Jäger, Erhard Seiler, Dénes Sexty, and Ion-Olimpiu Stamatescu. Qcd at nonzero chemical potential: recent
- progress on the lattice. December 2014.
Yue Zhao. Radiation hardened design of CMOS pixel sensor for the micro*vertex detector of the CBM experiment.* PhD thesis, Physics [physics]. Université de Strasbourg. English. NNT : 2021STRAE010. tel-03284188. 2021.
- Roma Bugiel. Latest results from mimosis-1. 41st CBM Collaboration Meeting in Darmstadt, march 2023.
- [5] Cyrcé platform website. https://cyrce.fr/en/home/.
- Marc Rousseau. Private communication, May 2023.
- [7] Jerôme Baudot. Taf short manual. Université de Strasbourg, IPHC, CNRS, UMR7178, https://github.com/zelbitar/taf.git., December 2020.
- [8] Julie Constanzo, Marie Vanstalle, Mathieu Guillot, Marc Rousseau, and Christian Finck. Characterization of a cmos sensor array for small field fluence measurement of a low energy proton beam. Nuclear Instruments and Methods in Physics Research Section A: Accelerators, Spectrometers, Detectors and Associated Equipment, 910:1-8, 2018.
- [9] D.E. Groom and S.R. Klein. Particle Data Group. Chapter 34. Passage of Particles through Matter. August 2021.
- [10] P. Allport, F. Bögelspacher, K. Bruce, R. Canavan, A. Dierlamm, L. Gonella, P. Knights, I. Mateu, M. Moll, K. Nikolopoulos, B. Phoenix, T. Price, L. Ram, F. Ravotti, C. Simpson-Allsop, and C. Wood. Experimental determination of proton hardness factors at several irradiation facilities. Journal of Instrumentation, 14(12):P12004, dec 2019.
- [11] M. Huhtinen and P.A. Aarnio. Proton induced displacement damage in silicon. https://rd50.web.cern.ch/NIEL/protons.pdf, 1993.

Values from ref. [10]

Difference LET and stopping power

- Stopping power: energy loss by the particle (in the matter),
- $LET: energy transferred$ locally by the particle to the material per unit length.

$$
LET = \left(\frac{dE}{dx}\right) - \sum \widehat{E_c(e_\delta)}.
$$

kinetic energies of the δ electrons having an energy higher than a threshold

For protons:

$$
\sum E_c(e_\delta) \approx 0 \Rightarrow \text{LET} \approx \left(\frac{\text{dE}}{\text{dx}}\right)
$$

NIEL factor

- Non-ionizing doses calculated by means of the NIEL (Non-Ionizing Energy Loss) factor,
- Normalizes the radiation damage caused by 1 MeV neutrons.
- Goal: Inter-facility comparison and collaboration.
- Derived by evaluating the leakage current in the bulk of a silicon sensor.
- For 25 MeV protons in Silicon: the NIEL factor is 2.558. *Figure from ref. [11]*

CBM and PICSEL

- **STS: Silicon Tracking System**
- RICH : Ring Imaging Cherenkov detector
- TRD : Transition Radiation **Detectors**
- MUCH : MUon tracking CHamber
- TOF : Time-Of-Flight detector
- ECAL : Electromagnetic Calorimeter
- PSD : Projectile Spectator **Detector**

Requirements :

Charm meson can't reach detector (cτ(D^o) = 123 μm) ⇒ Spatial resolution

Rare probe \rightarrow high intensity ⇒ Radiation resistant

Description of the MIMOSIS-1 sensor

Description of the sensor

N region: excess of electrons (on the valence band) P region : lack of electrons, or holes PN junction: electrons and holes recombine -> no free charges (depletion zone) -> barrier for charge carriers

N-region P-region **Very small** depletion layer Forward Biasing Voltage

Electrons flow from the n-type side to the p-type side, Reduce the depletion region increase the flow of current

Increases the depletion region Restrict the flow of current

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PN junction create a depletion zone (and therefore an electric field) to limit recombination when a charged particle passes through. Electron-hole pairs are collected easily by the detector's electrodes when the material is ionized.

Description of the sensor

Figure from ref. [4]

MIMOSIS timeline

MIMOSIS requirements

* without safety factor

Goals of the experiment

Efficiency as a function of the threshold

- \rightarrow different matrices
- \rightarrow different back-bias

Bandwidth saturation (number of events the sensor is able to process) as a function of the beam intensity.

Check the performances of the sensors under non uniform high rate radiation which is expected in the CBM experiment.

Determine the profile in fluence of the beam

- better qualify the sensors
- choose the best parameters for the final version of the MIMOSIS

better understand the deposited dose for radiobiology applications

beam

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Description of the other experiments

Change of threshold

Threshold : minimum number of electrons detected to interpret it as a signal

> high threshold \rightarrow some events can be missed. low threshold \rightarrow noise can be interpreted as signal.

Goal: analyse the efficiency as a function of this threshold.

Reference planes: threshold is 120 electrons (e-) *DUT:* measurements at 90 e-, 120 e-, 150 e-, 200 e-, 240 e-

Scan:

for each split (1, 3 and 4). for back bias on the DUT at -1 V and -3 V for matrix B and matrix C.

VCASN values for threshold

Description of the other experiments

Intensity scan

Goal: observe bandwidth saturation effect.

DUT: measurements from 18 to 2876 fA, (0.1 to 20 MHz/cm2).

Scan:

for split 1 and 3 for back bias on the DUT at -3 V for matrix B and matrix C.

Description of the other experiments

Irradiation resistivity

Goal: reproduce non-uniformity of MVD irradiations \rightarrow localized irradiations at high rate (fluence of 10^{13} and 10^{14} neg / cm²)

Long irradiation time (1h20) \rightarrow profile of the beam can vary

Irradiation configuration

Irradiation configuration

Profiles in fluence (X)

X profiles for different collimators

Figure F.2: X profile for different collimator diameters for bandlenght of 537 μ m.

X profiles for different collimators

Figure F.1: X profile for different collimator diameters for bandlenght of 71 μ m.

Y profiles for different collimators

Figure F.3: Y profile for different collimator diameters for bandlenght of 537 μ m.

Profiles in fluence: X and Y comparison

Profiles in fluence: distance scan intensity

Gafchromic calibration

Dose and fluence comparison $\rm{F.2}$

Figure F.4: Comparison of x profile of the beam in fluence and in dose for all collimators. The dose and fluence have been normalized.